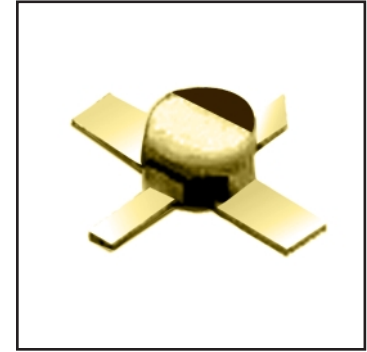


### FEATURES

- Low Noise Figure: 1.2B (Typ.)@f=12GHz
- High Associated Gain: 10.0dB (Typ.)@f=12GHz
- $L_g \leq 0.25\mu\text{m}$ ,  $W_g = 280\mu\text{m}$
- Gold Gate Metallization for High Reliability
- Cost Effective Ceramic Microstrip (SMT) Package
- Tape and Reel Packaging Available



### DESCRIPTION

The FHX35LG is a High Electron Mobility Transistor (HEMT) intended for general purpose, low noise and high gain amplifiers in the 2-18GHz frequency range. This device is packaged in cost effective, low parasitic, hermetically sealed (LG) or epoxy-sealed (LP) metal-ceramic packages for high volume telecommunication, DBS, TVRO, VSAT or other low noise applications.

Eudyna stringent Quality Assurance Program assures the highest reliability and consistent performance.

### ABSOLUTE MAXIMUM RATING (Ambient Temperature $T_a=25^\circ\text{C}$ )

Item	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	4.0	V
Gate-Source Voltage	$V_{GS}$	-3.0	V
Total Power Dissipation	$P_{t^*}$	290	mW
Storage Temperature	$T_{stg}$	-65 to +175	$^\circ\text{C}$
Channel Temperature	$T_{ch}$	175	$^\circ\text{C}$

\*Note: Mounted on  $\text{Al}_2\text{O}_3$  board (30 x 30 x 0.65mm)

Eudyna recommends the following conditions for the reliable operation of GaAs FETs:

1. The drain-source operating voltage ( $V_{DS}$ ) should not exceed 3 volts.
2. The forward and reverse gate currents should not exceed 0.2 and -0.075 mA respectively with gate resistance of  $4000\Omega$ .
3. The operating channel temperature ( $T_{ch}$ ) should not exceed  $80^\circ\text{C}$ .

### ELECTRICAL CHARACTERISTICS (Ambient Temperature $T_a=25^\circ\text{C}$ )

Item	Symbol	Test Conditions	Limit			Unit
			Min.	Typ.	Max.	
Saturated Drain Current	$I_{DSS}$	$V_{DS} = 2\text{V}$ , $V_{GS} = 0\text{V}$	15	40	85	mA
Transconductance	$g_m$	$V_{DS} = 2\text{V}$ , $I_{DS} = 10\text{mA}$	40	60	-	mS
Pinch-off Voltage	$V_p$	$V_{DS} = 2\text{V}$ , $I_{DS} = 1\text{mA}$	-0.2	-1.0	-2.0	V
Gate Source Breakdown Voltage	$V_{GSO}$	$I_{GS} = -10\mu\text{A}$	-3.0	-	-	V
Noise Figure	NF	$V_{DS} = 3\text{V}$ , $I_{DS} = 10\text{mA}$ $f = 12\text{GHz}$	-	1.2	1.6	dB
Associated Gain	$G_{as}$		8.5	10.0	-	dB
Thermal Resistance	$R_{th}$	Channel to Case	-	220	300	$^\circ\text{C}/\text{W}$

### AVAILABLE CASE STYLES: LG

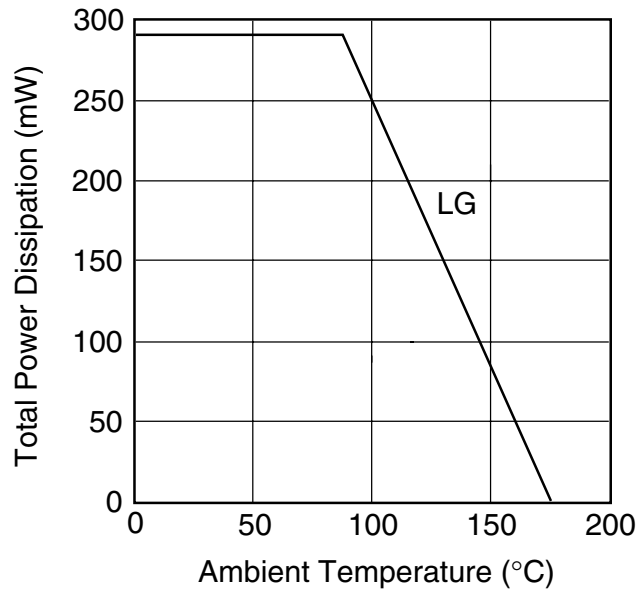
Note: RF parameters are measured on a sample basis as follows:

Lot qty.	Sample qty.	Accept/Reject
1200 or less	125	(0,1)
1201 to 3200	200	(0,1)
3201 to 10000	315	(1,2)
10001 or over	500	(1,2)

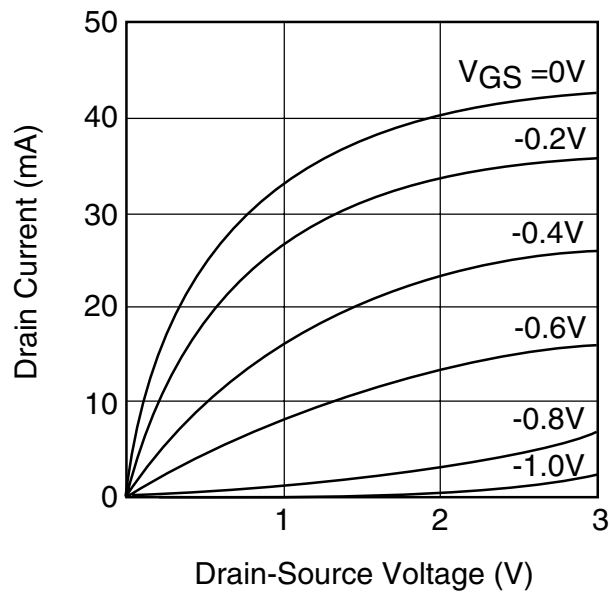
# FHX35LG

Super Low Noise HEMT

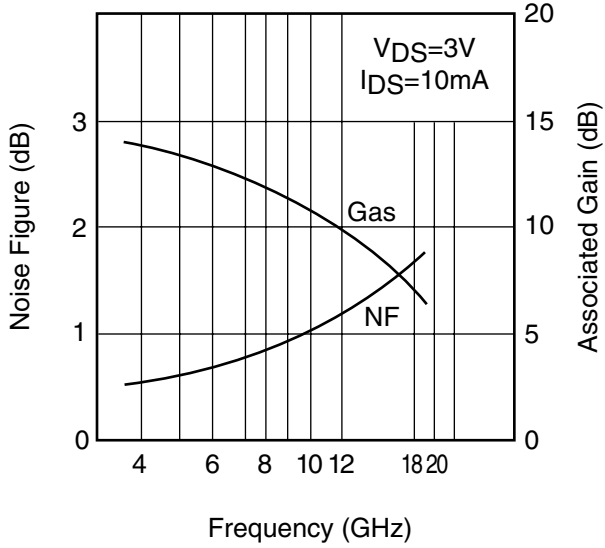
POWER DERATING CURVE



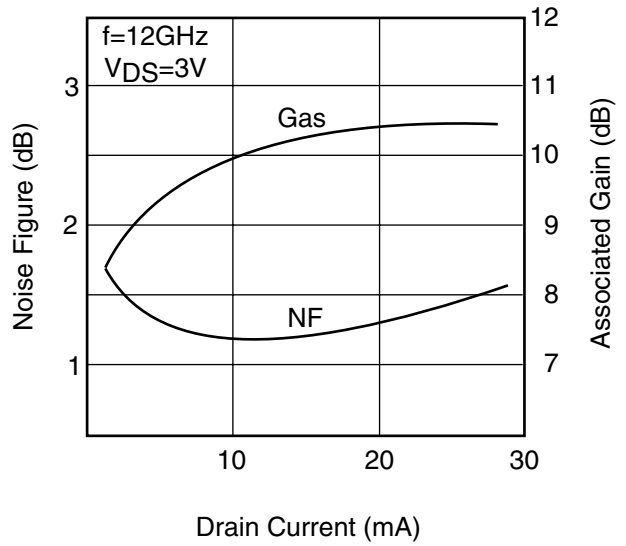
DRAIN CURRENT vs. DRAIN-SOURCE VOLTAGE



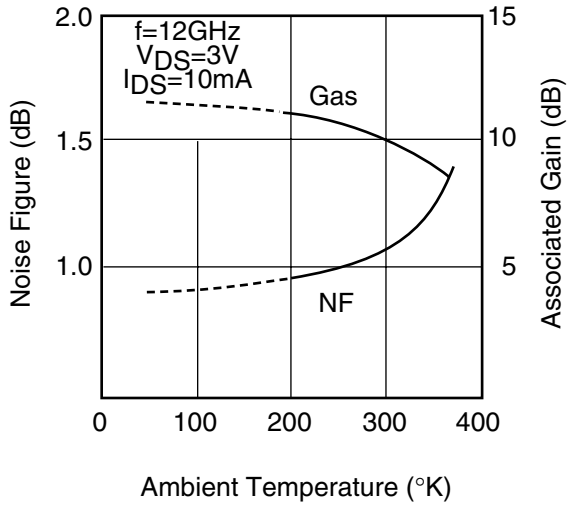
**NF & Gas vs. FREQUENCY**



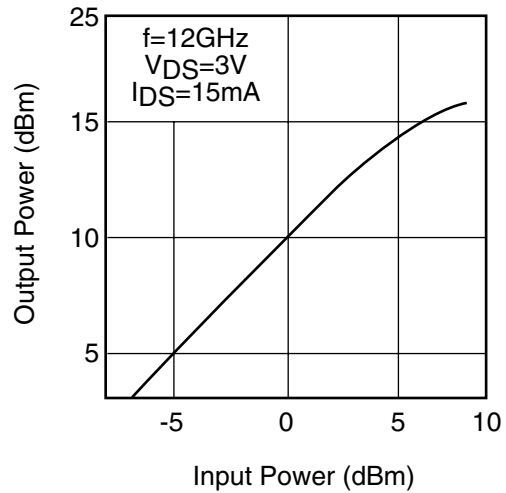
**NF & Gas vs.  $I_{DS}$**



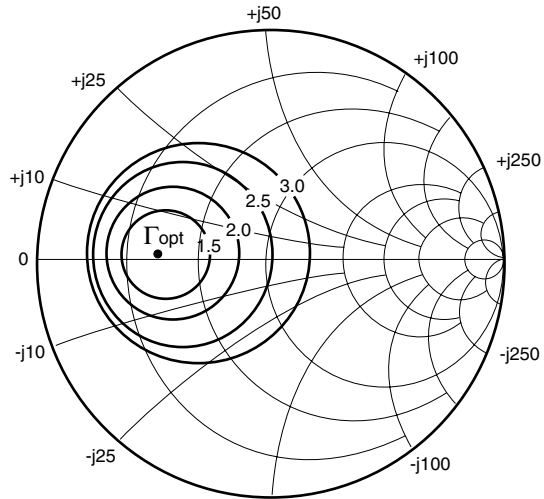
**NF & Gas vs. TEMPERATURE**



**OUTPUT POWER vs. INPUT POWER**



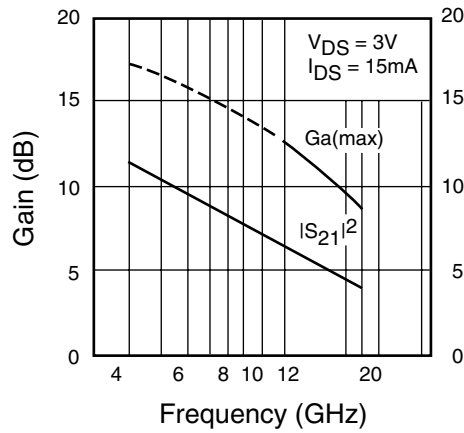
### TYPICAL NOISE FIGURE CIRCLE



f = 12 GHz  
 $V_{DS} = 3V$   
 $I_{DS} = 10mA$

$\Gamma_{opt} = 0.56 \angle 175^\circ$   
 $Rn/50 = 0.08$   
 $NF_{min} = 1.2dB$

### Ga(max) AND $|S_{21}|^2$ vs. FREQUENCY



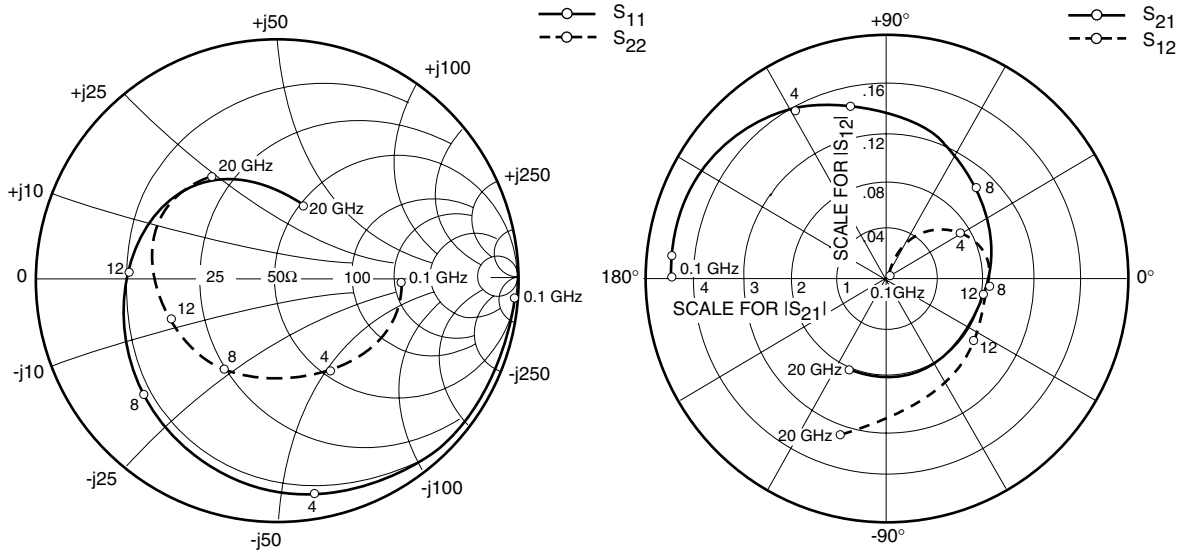
### NOISE PARAMETERS

$V_{DS} = 3V, I_{DS} = 10mA$

Freq. (GHz)	$\Gamma_{opt}$		NFmin (dB)	Rn/50
	(MAG)	(ANG)		
2	0.81	32	0.40	0.58
4	0.74	63	0.50	0.42
6	0.69	93	0.68	0.30
8	0.64	127	0.86	0.20
10	0.60	148	1.03	0.12
12	0.56	175	1.20	0.08
14	0.53	-162	1.38	0.08
16	0.50	-139	1.54	0.10
18	0.48	-117	1.70	0.14

# FHX35LG

## Super Low Noise HEMT



### S-PARAMETERS

$V_{DS} = 3V, I_{DS} = 10mA$

FREQUENCY (MHZ)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	.996	-3.5	4.576	177.2	.002	81.2	.516	-2.5
500	.994	-12.1	4.548	169.0	.012	79.3	.517	-10.2
1000	.982	-23.5	4.471	158.5	.023	73.1	.513	-19.9
2000	.950	-44.7	4.304	139.3	.043	57.9	.498	-38.0
3000	.912	-64.6	4.026	121.0	.059	44.6	.483	-54.9
4000	.867	-84.0	3.742	103.1	.071	31.8	.462	-71.9
5000	.821	-101.6	3.436	86.6	.079	20.0	.446	-87.6
6000	.783	-117.5	3.132	71.6	.085	9.8	.439	-102.2
7000	.757	-130.9	2.881	57.9	.087	0.9	.441	-115.3
8000	.738	-142.8	2.659	45.0	.088	-7.1	.452	-126.7
9000	.726	-153.8	2.497	32.4	.090	-15.3	.468	-136.9
10000	.707	-164.5	2.347	20.2	.092	-21.7	.480	-146.1
11000	.680	-174.1	2.206	8.4	.090	-27.8	.494	-156.0
12000	.654	176.1	2.101	-3.4	.090	-35.5	.503	-164.8
13000	.638	166.0	2.035	-15.1	.091	-42.6	.514	-173.8
14000	.626	157.1	2.003	-26.2	.093	-49.6	.537	178.4
15000	.607	147.8	1.975	-37.6	.094	-55.8	.559	171.0
16000	.565	138.4	1.917	-50.1	.097	-64.7	.564	162.7
17000	.528	127.2	1.924	-62.9	.102	-73.3	.567	154.4
18000	.484	112.8	1.966	-77.1	.109	-86.2	.572	142.7
19000	.421	93.5	1.932	-91.7	.116	-96.2	.581	133.1
20000	.380	74.2	1.991	-107.4	.127	-110.9	.547	124.3

